


	<b>NSVBC114EPDXV6T1G</b>	
	<b>Hersteller-Teilenummer:</b>	NSVBC114EPDXV6T1G
	<b>Hersteller / Marke:</b>	AMI Semiconductor / ON Semiconductor
	<b>Teil der Beschreibung:</b>	TRANS NPN/PNP BIAS SOT563
	<b>Datenblätter:</b>	 <a href="#">NSVBC114EPDXV6T1G.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
	<b>Lagerzustand:</b>	New original, 4000 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

### Spezifikationen

Teilenummer	NSVBC114EPDXV6T1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS NPN/PNP BIAS SOT563
Kategorie	Diskrete Halbleiterprodukte > Transistoren-bipolare
Teilstatus	4000 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Leistung - max	500mW
Verpackung / Gehäuse	SOT-563, SOT-666
Supplier Device-Gehäuse	SOT-563
Transistor-Typ	1 NPN, 1 PNP - Pre-Biased (Dual)
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	250mV @ 300µA, 10mA
Strom - Collector Cutoff (Max)	500nA
DC Stromgewinn (HFE) (Min) @ Ic, VCE	35 @ 5mA, 10V
Frequenz - Übergang	-
Widerstand - Base (R1) (Ohm)	10k
Widerstand - Emitter-Basis (R2) (Ohm)	10k
Verpackung	Tape & Reel (TR)





















NSVBC114EPDXV6T1G ist neu im Original, Suche NSVBC114EPDXV6T1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NSVBC114EPDXV6T1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NSVBC114EPDXV6T1G: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NSVBC114YDPDXV6T1G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP 50V SOT563</p>	 <p><b>NSVBAV70DXV6T5G</b> AMI Semiconductor / ON Semiconductor DIODE ARRAY GP 70V 200MA SOT563</p>	 <p><b>NSVBC123JPDV6T1G</b> AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN/PNP 50V SOT563</p>	 <p><b>NSVBC124EDXV6T1G</b> AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563</p>
 <p><b>NSVBAV99WT3G</b> AMI Semiconductor / ON Semiconductor DIODE ARRAY GP 99V 200MA SC70</p>	 <p><b>NSVBAV70TT1G</b> AMI Semiconductor / ON Semiconductor DIODE ARRAY SW 100V 100MA SC75</p>	 <p><b>NSVBC114EDXV6T1G</b> AMI Semiconductor / ON Semiconductor TRANS 2NPN BIAS BIPOLAR SOT563</p>	 <p><b>NSVBC114YDXV6T1G</b> AMI Semiconductor / ON Semiconductor TRANS 2NPN PREBIAS 0.5W SOT563</p>

### heiße Teile

Mehr

 NSV12200LT1G	 NSV12201LT1G	 NSV1C200LT1G	 NSV1C200MZ4T1G	 NSV1C201LT1G
 NSV1C201MZ4T1G	 NSV1C300ET4G	 NSV1C301ET4G	 NSV20200LT1G	 NSV20201LT1G
 NSV40200LT1G	 NSV40201LT1G	 NSV40300MZ4T1G	 NSV40301MZ4T1G	 NSV60200LT1G
 NSV60201LT1G	 NSV60600MZ4T1G	 NSV60601MZ4T1G	 NSVBAS19LT1G	 NSVBAS21HT1G
 NSVBAS21HT3G	 NSVBAS21M3T5G	 NSVBAS21SLT1G	 NSVBAS21TMR6T2G	 NSVBAS70LT1
 NSVBAS70LT1G	 NSVBAT54HT1	 NSVBAT54HT1G	 NSVBAT54LT1G	 NSVBAT54M3T5G
 NSVBAT54SWT1G	 NSVBAT54WT1G	 NSVBAV23CLT1G	 NSVBAV70TT3G	 NSVBAV99WT3G
 NSVBC817-40WT1G	 NSVBC818-40LT1G	 NSVBC848BWT1G	 NSVBC848CLT1G	 NSVBC849BLT1G
 NSVBC850BLT1G	 NSVBC850CLT1G	 NSVBC857CWT1G	 NSVBC858AWT1G	 NSVBC858BLT1G
 NSVBC858CLT1G	 NSVBPC69T1G	 NSVBCW68GLT1G	 NSVBCX17LT1G	 NSVF2250WT1G

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